

### FEATURES

**True RMS-to-DC Conversion**

**Laser-Trimmed to High Accuracy**

**0.2% Max Error (AD536AK)**

**0.5% Max Error (AD536AJ)**

**Wide Response Capability:**

**Computes RMS of AC and DC Signals**

**450 kHz Bandwidth:  $V_{rms} > 100\text{ mV}$**

**2 MHz Bandwidth:  $V_{rms} > 1\text{ V}$**

**Signal Crest Factor of 7 for 1% Error**

**dB Output with 60 dB Range**

**Low Power: 1.2 mA Quiescent Current**

**Single or Dual Supply Operation**

**Monolithic Integrated Circuit**

**-55°C to +125°C Operation (AD536AS)**

### PRODUCT DESCRIPTION

The AD536A is a complete monolithic integrated circuit which performs true rms-to-dc conversion. It offers performance which is comparable or superior to that of hybrid or modular units costing much more. The AD536A directly computes the true rms value of any complex input waveform containing ac and dc components. It has a crest factor compensation scheme which allows measurements with 1% error at crest factors up to 7. The wide bandwidth of the device extends the measurement capability to 300 kHz with 3 dB error for signal levels above 100 mV.

An important feature of the AD536A not previously available in rms converters is an auxiliary dB output. The logarithm of the rms output signal is brought out to a separate pin to allow the dB conversion, with a useful dynamic range of 60 dB. Using an externally supplied reference current, the 0 dB level can be conveniently set by the user to correspond to any input level from 0.1 to 2 volts rms.

The AD536A is laser trimmed at the wafer level for input and output offset, positive and negative waveform symmetry (dc reversal error), and full-scale accuracy at 7 V rms. As a result, no external trims are required to achieve the rated unit accuracy.

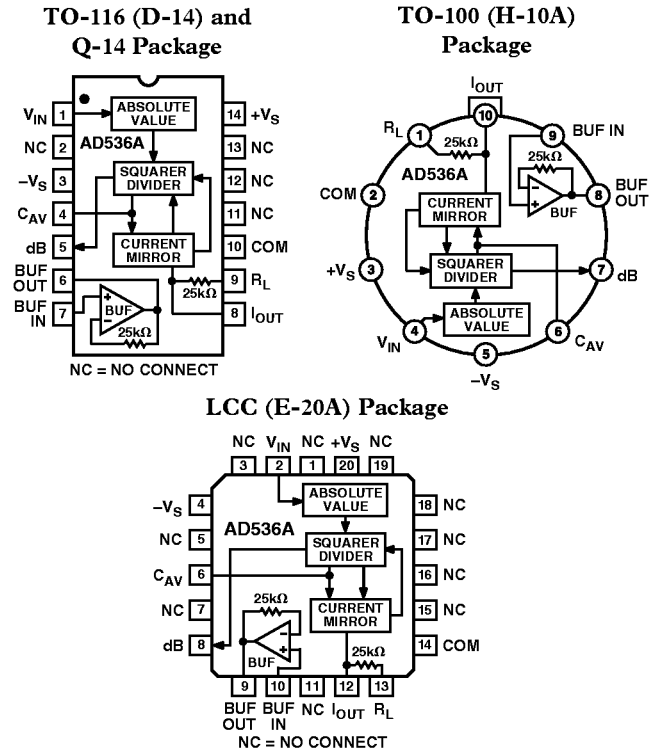
There is full protection for both inputs and outputs. The input circuitry can take overload voltages well beyond the supply levels. Loss of supply voltage with inputs connected will not cause unit failure. The output is short-circuit protected.

The AD536A is available in two accuracy grades (J, K) for commercial temperature range (0°C to +70°C) applications, and one grade (S) rated for the -55°C to +125°C extended range. The AD536AK offers a maximum total error of  $\pm 2\text{ mV} \pm 0.2\%$  of reading, and the AD536AJ and AD536AS have maximum errors of  $\pm 5\text{ mV} \pm 0.5\%$  of reading. All three versions are available in either a hermetically sealed 14-lead DIP or 10-pin TO-100 metal can. The AD536AS is also available in a 20-leadless hermetically sealed ceramic chip carrier.

### REV. B

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### PIN CONFIGURATIONS AND FUNCTIONAL BLOCK DIAGRAMS



### PRODUCT HIGHLIGHTS

1. The AD536A computes the true root-mean-square level of a complex ac (or ac plus dc) input signal and gives an equivalent dc output level. The true rms value of a waveform is a more useful quantity than the average rectified value since it relates directly to the power of the signal. The rms value of a statistical signal also relates to its standard deviation.
2. The crest factor of a waveform is the ratio of the peak signal swing to the rms value. The crest factor compensation scheme of the AD536A allows measurement of highly complex signals with wide dynamic range.
3. The only external component required to perform measurements to the fully specified accuracy is the capacitor which sets the averaging period. The value of this capacitor determines the low frequency ac accuracy, ripple level and settling time.
4. The AD536A will operate equally well from split supplies or a single supply with total supply levels from 5 to 36 volts. The one milliampere quiescent supply current makes the device well-suited for a wide variety of remote controllers and battery powered instruments.
5. The AD536A directly replaces the AD536 and provides improved bandwidth and temperature drift specifications.

# AD536A—SPECIFICATIONS (@ +25°C, and ±15 V dc unless otherwise noted)

Model	AD536AJ			AD536AK			AD536AS			Units
	Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
TRANSFER FUNCTION										
CONVERSION ACCURACY	$V_{OUT} = \sqrt{avg. (V_{IN})^2}$			$V_{OUT} = \sqrt{avg. (V_{IN})^2}$			$V_{OUT} = \sqrt{avg. (V_{IN})^2}$			
Total Error, Internal Trim <sup>1</sup> (Figure 1) vs. Temperature, T <sub>MIN</sub> to +70°C +70°C to +125°C	±5 ±0.5 ±0.1 ±0.01			±2 ±0.2 ±0.05 ±0.005			±5 ±0.5 ±0.1 ±0.005 ±0.3 ±0.005			mV ± % of Reading mV ± % of Reading/°C mV ± % of Reading/V ± % of Reading mV ± % of Reading
vs. Supply Voltage	±0.1 ±0.01			±0.1 ±0.01			±0.1 ±0.01			
dc Reversal Error	±0.2			±0.1			±0.2			
Total Error, External Trim <sup>1</sup> (Figure 2)	±3 ±0.3			±2 ±0.1			±3 ±0.3			
ERROR VS. CREST FACTOR <sup>2</sup>	Specified Accuracy			Specified Accuracy			Specified Accuracy			
Crest Factor 1 to 2	-0.1			-0.1			-0.1			% of Reading
Crest Factor = 3	-1.0			-1.0			-1.0			% of Reading
Crest Factor = 7										
FREQUENCY RESPONSE <sup>3</sup>										
Bandwidth for 1% Additional Error (0.09 dB)										
V <sub>IN</sub> = 10 mV	5			5			5			kHz
V <sub>IN</sub> = 100 mV	45			45			45			kHz
V <sub>IN</sub> = 1 V	120			120			120			kHz
±3 dB Bandwidth										
V <sub>IN</sub> = 10 mV	90			90			90			kHz
V <sub>IN</sub> = 100 mV	450			450			450			kHz
V <sub>IN</sub> = 1 V	2.3			2.3			2.3			MHz
AVERAGING TIME CONSTANT (Figure 5)	25			25			25			ms/μF CAV
INPUT CHARACTERISTICS										
Signal Range, ±15 V Supplies	0 to 7			0 to 7			0 to 7			V rms
Continuous rms Level										V rms
Peak Transient Input	±20			±20			±20			V peak
Continuous rms Level, ±5 V Supplies	0 to 2			0 to 2			0 to 2			V rms
Peak Transient Input, ±5 V Supplies	±7			±7			±7			V peak
Maximum Continuous Nondestructive Input Level (All Supply Voltages)	±25			±25			±25			V peak
Input Resistance	13.33	16.67	20	13.33	16.67	20	13.33	16.67	20	kΩ
Input Offset Voltage	0.8 ±2			0.5 ±1			0.8 ±2			mV
OUTPUT CHARACTERISTICS										
Offset Voltage, V <sub>IN</sub> = COM (Figure 1) vs. Temperature	±1 ±0.1			±0.5 ±0.1			±2 ±0.2			mV mV/°C
vs. Supply Voltage	±0.1			±0.1			±0.2			mV/V
Voltage Swing, ±15 V Supplies	0 to +11	+12.5		0 to +11	+12.5		0 to +11	+12.5		V
±5 V Supply	0 to +2			0 to +2			0 to +2			V
dB OUTPUT (Figure 13)										
Error, V <sub>IN</sub> 7 mV to 7 V rms, 0 dB = 1 V rms	±0.4 -3			±0.2 -3			±0.5 -3			dB mV/dB
Scale Factor										
Scale Factor TC (Uncompensated, see Figure 1 for Temperature Compensation)	-0.033 +0.33			-0.033 +0.33			-0.033 +0.33			dB/°C % of Reading/°C
I <sub>REF</sub> for 0 dB = 1 V rms	5	20	80	5	20	80	5	20	80	μA
I <sub>REF</sub> Range	1 to 100			1 to 100			1 to 100			μA
I <sub>OUT</sub> TERMINAL										
I <sub>OUT</sub> Scale Factor	40			40			40			μA/V rms
I <sub>OUT</sub> Scale Factor Tolerance	±10 ±20			±10 ±20			±10 ±20			%
Output Resistance	20	25	30	20	25	30	20	25	30	kΩ
Voltage Compliance	-V <sub>S</sub> to (+V <sub>S</sub> -2.5 V)			-V <sub>S</sub> to (+V <sub>S</sub> -2.5 V)			-V <sub>S</sub> to (+V <sub>S</sub> -2.5 V)			V
BUFFER AMPLIFIER										
Input and Output Voltage Range	-V <sub>S</sub> to (+V <sub>S</sub> -2.5 V)			-V <sub>S</sub> to (+V <sub>S</sub> -2.5 V)			-V <sub>S</sub> to (+V <sub>S</sub> -2.5 V)			V
Input Offset Voltage, R <sub>S</sub> = 25 k	±0.5 ±4			±0.5 ±4			±0.5 ±4			mV
Input Bias Current	20 60			20 60			20 60			nA
Input Resistance	10 <sup>8</sup>			10 <sup>8</sup>			10 <sup>8</sup>			Ω
Output Current	(+5 mA, -130 μA)			(+5 mA, -130 μA)			(+5 mA, -130 μA)			
Short Circuit Current	20			20			20			mA
Output Resistance	0.5			0.5			0.5			Ω
Small Signal Bandwidth	1			1			1			MHz
Slew Rate*	5			5			5			V/μs
POWER SUPPLY										
Voltage Rated Performance	±15			±15			±15			V
Dual Supply	±3.0		±18	±3.0		±18	±3.0		±18	V
Single Supply	+5		+36	+5		+36	+5		+36	V
Quiescent Current										
Total V <sub>S</sub> , 5 V to 36 V, T <sub>MIN</sub> to T <sub>MAX</sub>	1.2 2			1.2 2			1.2 2			mA
TEMPERATURE RANGE										
Rated Performance	0 +70			0 +70			-55 +125			°C
Storage	-55 +150			-55 +150			-55 +150			°C
NUMBER OF TRANSISTORS	65			65			65			

## NOTES

<sup>1</sup>Accuracy is specified for 0 V to 7 V rms, dc or 1 kHz sine wave input with the AD536A connected as in the figure referenced.

<sup>2</sup>Error vs. crest factor is specified as an additional error for 1 V rms rectangular pulse input, pulsewidth = 200 μs.

<sup>3</sup>Input voltages are expressed in volts rms, and error is percent of reading.

\*With 2k external pull-down resistor.

Specifications subject to change without notice.

Specifications shown in **boldface** are tested on all production units at final electrical test. Results from those tests are used to calculate outgoing quality levels. All min and max specifications are guaranteed, although only those shown in boldface are tested on all production units.

## ABSOLUTE MAXIMUM RATINGS<sup>1</sup>

Supply Voltage	
Dual Supply	±18 V
Single Supply	+36 V
Internal Power Dissipation <sup>2</sup>	500 mW
Maximum Input Voltage	±25 V Peak
Buffer Maximum Input Voltage	±V <sub>S</sub>
Maximum Input Voltage	±25 V Peak
Storage Temperature Range	-55°C to +150°C
Operating Temperature Range	
AD536AJ/K	0°C to +70°C
AD536AS	-55°C to +125°C
Lead Temperature Range	
(Soldering 60 sec)	+300°C
ESD Rating	1000 V

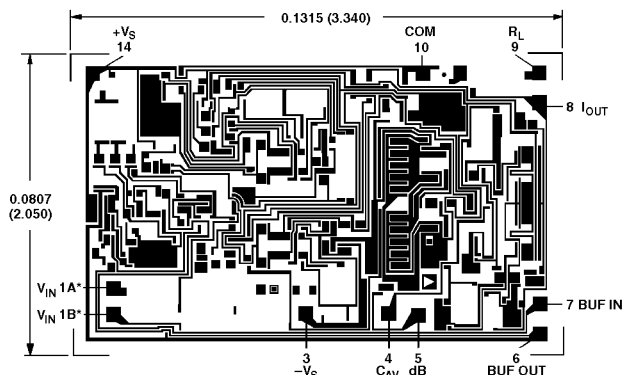
## NOTES

<sup>1</sup>Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

<sup>2</sup>10-Pin Header:  $\theta_{JA} = 150^\circ\text{C/W}$ ; 20-Leadless LCC:  $\theta_{JA} = 95^\circ\text{C/W}$ ; 14-Lead Size Brazed Ceramic DIP:  $\theta_{JA} = 95^\circ\text{C/W}$ .

## CHIP DIMENSIONS AND PAD LAYOUT

Dimensions shown in inches and (mm).



PAD NUMBERS CORRESPOND TO PIN NUMBERS FOR THE TO-166 14-LEAD CERAMIC DIP PACKAGE.  
NOTE  
\*BOTH PADS SHOWN MUST BE CONNECTED TO V<sub>IN</sub>.  
THE AD536A IS AVAILABLE IN LASER TRIMMED CHIP FORM.  
SUBSTRATE CONNECTED TO -V<sub>S</sub>.

## ORDERING GUIDE

Model	Temperature Range	Package Description	Package Option
AD536AJD	0°C to +70°C	Side Brazed Ceramic DIP	D-14
AD536AKD	0°C to +70°C	Side Brazed Ceramic DIP	D-14
AD536AJH	0°C to +70°C	Header	H-10A
AD536AKH	0°C to +70°C	Header	H-10A
AD536AJQ	0°C to +70°C	Cerdip	Q-14
AD536AKQ	0°C to +70°C	Cerdip	Q-14
AD536ASD	-55°C to +125°C	Side Brazed Ceramic DIP	D-14
AD536ASD/883B	-55°C to +125°C	Side Brazed Ceramic DIP	D-14
AD536ASE/883B	-55°C to +125°C	LCC	E-20A
AD536ASH	-55°C to +125°C	Header	H-10A
AD536ASH/883B	-55°C to +125°C	Header	H-10A
AD536AJCHIPS	0°C to +70°C	Die	
AD536AKH/+	0°C to +70°C	Header	H-10A
AD536ASCHIPS	-55°C to +125°C	Die	
5962-89805012A	-55°C to +125°C	LCC	E-20A
5962-8980501CA	-55°C to +125°C	Side Brazed Ceramic DIP	D-14
5962-8980501IA	-55°C to +125°C	Header	H-10A

## STANDARD CONNECTION

The AD536A is simple to connect for the majority of high accuracy rms measurements, requiring only an external capacitor to set the averaging time constant. The standard connection is shown in Figure 1. In this configuration, the AD536A will measure the rms of the ac and dc level present at the input, but will show an error for low frequency inputs as a function of the filter capacitor, C<sub>AV</sub>, as shown in Figure 5. Thus, if a 4 μF capacitor is used, the additional average error at 10 Hz will be 0.1%, at 3 Hz it will be 1%. The accuracy at higher frequencies will be according to specification. If it is desired to reject the dc input, a capacitor is added in series with the input, as shown in Figure 3, the capacitor must be nonpolar. If the AD536A is driven with power supplies with a considerable amount of high frequency ripple, it is advisable to bypass both supplies to ground with 0.1 μF ceramic discs as near the device as possible.

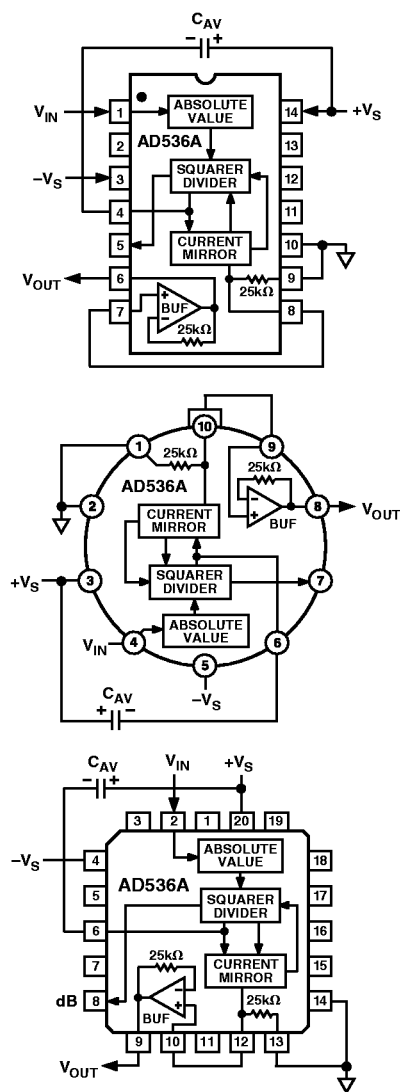


Figure 1. Standard RMS Connection



factors, (such as low duty cycle pulse trains), the averaging time constant should be at least ten times the signal period. For example, a 100 Hz pulse rate requires a 100 ms time constant, which corresponds to a 4  $\mu\text{F}$  capacitor (time constant = 25 ms per  $\mu\text{F}$ ).

The primary disadvantage in using a large  $C_{AV}$  to remove ripple is that the settling time for a step change in input level is increased proportionately. Figure 5 shows that the relationship between  $C_{AV}$  and 1% settling time is 115 milliseconds for each microfarad of  $C_{AV}$ . The settling time is twice as great for decreasing signals as for increasing signals (the values in Figure 5 are for decreasing signals). Settling time also increases for low signal levels, as shown in Figure 6.

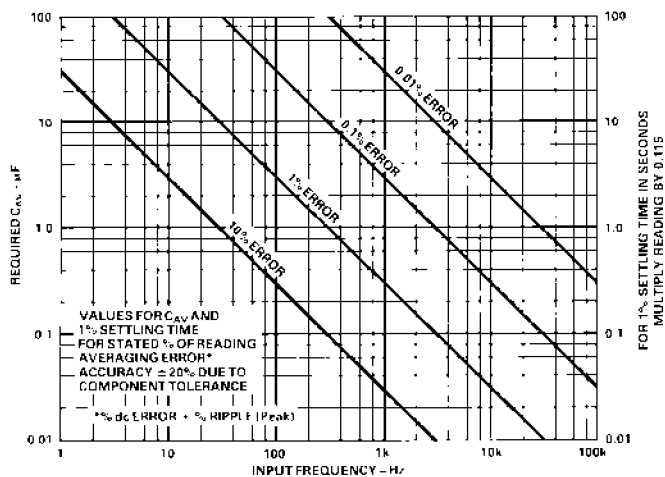


Figure 5. Error/Settling Time Graph for Use with the Standard rms Connection in Figure 1

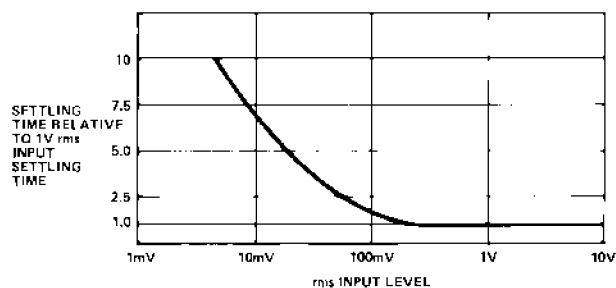


Figure 6. Settling Time vs. Input Level

A better method for reducing output ripple is the use of a "post-filter." Figure 7 shows a suggested circuit. If a single-pole filter is used ( $C_3$  removed,  $R_x$  shorted), and  $C_2$  is approximately twice the value of  $C_{AV}$ , the ripple is reduced as shown in Figure 8 and settling time is increased. For example, with  $C_{AV} = 1 \mu\text{F}$  and  $C_2 = 2.2 \mu\text{F}$ , the ripple for a 60 Hz input is reduced from 10% of reading to approximately 0.3% of reading. The settling time, however, is increased by approximately a factor of 3. The values of  $C_{AV}$  and  $C_2$  can, therefore, be reduced to permit faster settling times while still providing substantial ripple reduction.

The two-pole post-filter uses an active filter stage to provide even greater ripple reduction without substantially increasing the settling times over a circuit with a one-pole filter. The values of  $C_{AV}$ ,  $C_2$ , and  $C_3$  can then be reduced to allow extremely fast settling times for a constant amount of ripple. Caution should be exercised in choosing the value of  $C_{AV}$ , since the dc error is dependent upon this value and is independent of the post filter.

For a more detailed explanation of these topics refer to the *RMS to DC Conversion Application Guide 2nd Edition*, available from Analog Devices.

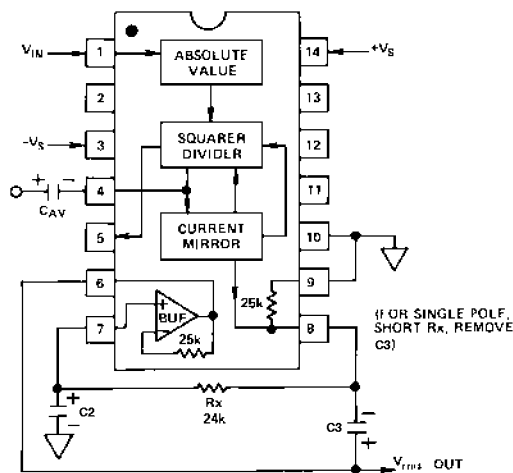


Figure 7. 2-Pole "Post" Filter

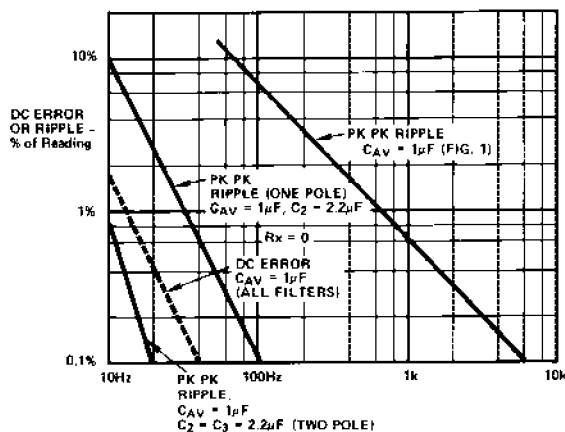


Figure 8. Performance Features of Various Filter Types

## AD536A PRINCIPLE OF OPERATION

The AD536A embodies an implicit solution of the rms equation that overcomes the dynamic range as well as other limitations inherent in a straightforward computation of rms. The actual computation performed by the AD536A follows the equation:

$$V_{rms} = Avg. \left[ \frac{V_{IN}^2}{V_{rms}} \right]$$



**FREQUENCY RESPONSE**

The AD536A utilizes a logarithmic circuit in performing the implicit rms computation. As with any log circuit, bandwidth is proportional to signal level. The solid lines in the graph below represent the frequency response of the AD536A at input levels from 10 millivolts to 7 volts rms. The dashed lines indicate the upper frequency limits for 1%, 10%, and 3 dB of reading additional error. For example, note that a 1 volt rms signal will produce less than 1% of reading additional error up to 120 kHz. A 10 millivolt signal can be measured with 1% of reading additional error (100  $\mu$ V) up to only 5 kHz.

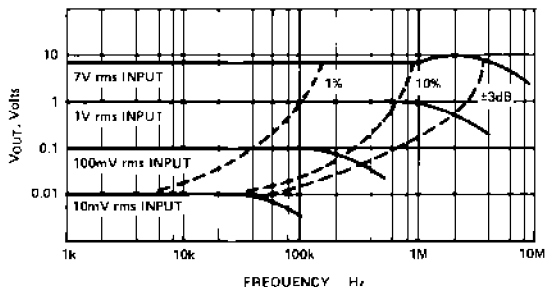


Figure 11. High Frequency Response

**AC MEASUREMENT ACCURACY AND CREST FACTOR**

Crest factor is often overlooked in determining the accuracy of an ac measurement. Crest factor is defined as the ratio of the peak signal amplitude to the rms value of the signal ( $CF = V_p / V_{rms}$ ). Most common waveforms, such as sine and triangle waves, have relatively low crest factors ( $<2$ ). Waveforms which resemble low duty cycle pulse trains, such as those occurring in switching power supplies and SCR circuits, have high crest factors. For example, a rectangular pulse train with a 1% duty cycle has a crest factor of 10 ( $CF = 1/\sqrt{\eta}$ ).

Figure 12 is a curve of reading error for the AD536A for a 1 volt rms input signal with crest factors from 1 to 11. A rectangular pulse train (pulsewidth 100  $\mu$ s) was used for this test since it is the worst-case waveform for rms measurement (all the energy is contained in the peaks). The duty cycle and peak amplitude were varied to produce crest factors from 1 to 11 while maintaining a constant 1 volt rms input amplitude.

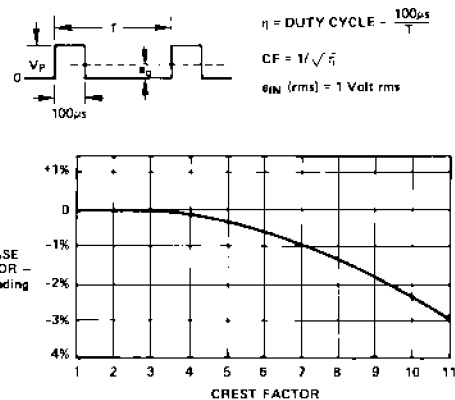


Figure 12. Error vs. Crest Factor

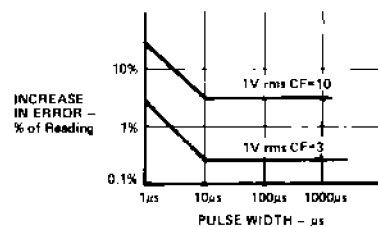


Figure 13. AD536A Error vs. Pulsewidth Rectangular Pulse

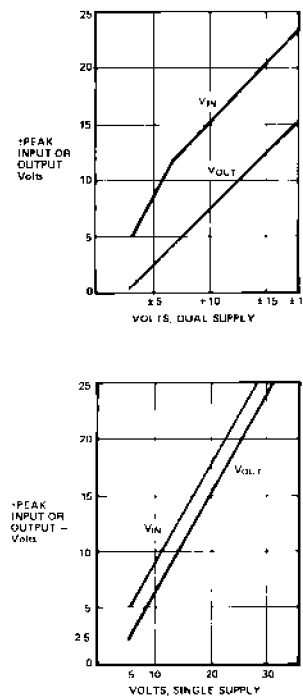
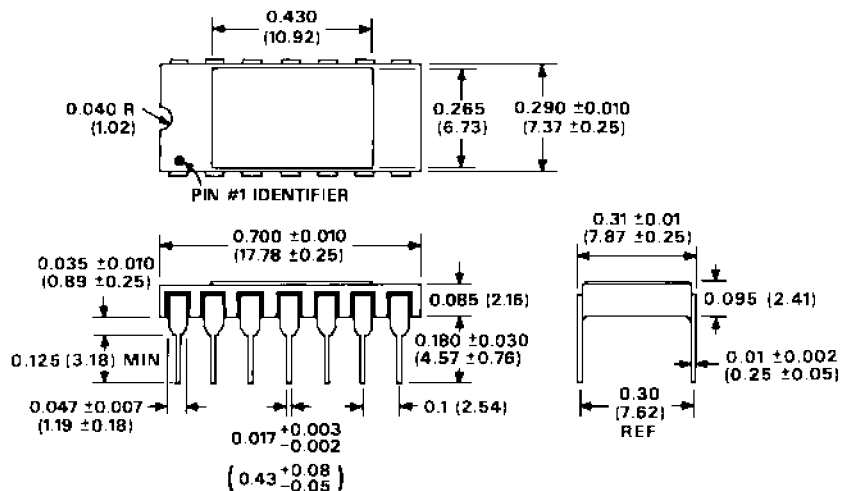


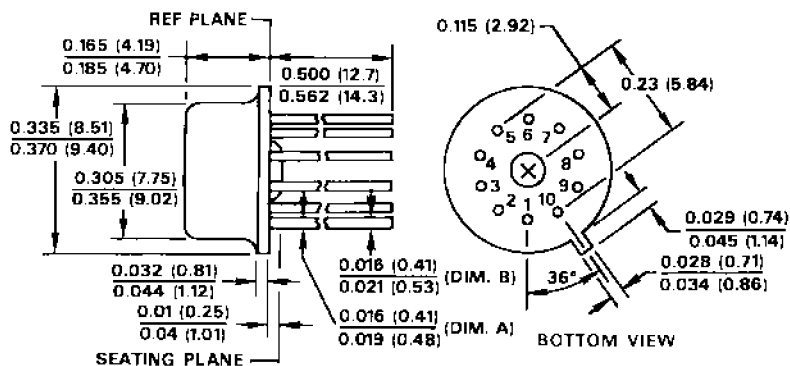
Figure 14. AD536A Input and Output Voltage Ranges vs. Supply

**OUTLINE DIMENSIONS**  
Dimensions shown in inches and (mm).

**D-14 Package**  
**TO-116**



**H-10A Package**  
**TO-100**



**E-20A Package**  
**LCC**

